EXCITON MAGNETOPHOTOLUMINESCENCE STUDY ON THE Mn-Mn PAIR INTERACTION IN $Cd_{0.95}Mn_{0.05}Se$ UNDER HIGH PRESSURES

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ABSTRACT

The pressure dependence of the exciton magnetophotoluminescence is studied in $\mathrm{Cd}_{usy}\mathrm{Mn}_{oos}\mathrm{Se}$ with attention focused on the pressure effects on the stepwise magnetization of the nearest-neighbor Mn-Mn pairs. The Mn-Mn superexchange interaction, as well as the exciton-Mn exchange interaction, is found to be strengthened by pressure. The pressure coefficients of the exchange constants indicate that the effective Coulomb energy U of Mn ions and the charge-transfer energy Δ are reduced by pressure.

1. Introduction

It has emerged from recent magnetophotoluminescence studies of II-VI diluted magnetic semiconductors that the exchange interaction between an exciton and transition-metal (TM) ions is strengthened by hydrostatic pressure. ^{1,2} Although a large part of the observed effect can be explained in terms of the bond-length dependence of the p-d transfer integral V_{pd} , it is suggested that the effective Coulomb energy U of d electrons of TM ions and/or the charge-transfer energy Δ between the upper Hubbard state of TM ions and the topmost edge of the valence band are also affected by pressure. ¹ In order to obtain further information on this problem, we study the pressure effects on the magnetization steps ³ due to the Mn-Mn pairs in $Cd_{0.05}Mn_{0.05}$ Se by the exciton magnetophotoluminescence method.

2. Experiment

Pressure is generated with a diamond anvil cell. A hydrostatic environment is obtained by using condensed argon as the pressure-transmitting medium. The maximum pressure is limited to 2 GPa in order to sustain the wurtzite structure. The diamond anvil cell is immersed in superfluid He at 1.4 K. The static magnetic field of up to 25 T is generated with a hybrid magnet, and is applied parallel to the c-axis of the sample. The excitation and detection of the photoluminescence are performed with fiber-optic apparatus. ⁴

3. Results and Discussion

Figure 1 shows the magnetic-field dependence of the photoluminescence spectrum due to the A-exciton at 0 and 1.9 GPa. In Fig.2 is plotted the field-induced energy shift $\delta E_{\rm A}$ of the free exciton line (F) observed under several pressures. At any pressure the

energy shift is almost leveled in the field region above 6 T, since the thermal average <S> of the spins of isolated Mn ions is saturated under high magnetic fields. We see that pressure enhances $\delta E_{\rm a}$. This is due to the enhancement of the exciton-Mn exchange interaction^{1,2} that is dominated by the hole-Mn kinetic spin interaction,⁵ i.e., the hybridization term of the p-d exchange interaction. In addition, the weak stepwise magnetization of the antiferromagnetically coupled Mn ions, which are substituted for the nearest-neighbor cations, can also be identified in the field dependence of δE_{Δ} above 10 T. The stepwise anomalies of magnetization occur successively at magnetic fields $H_n(n=1, 2, ...5)$ at which the total spin S_n of the ground state of the paired Mn ions increases from n-1 to n as a result of the energy-level crossing. The derivative $-dE_A/dH$ is plotted as a function of the external field H in the inset of Fig.2. It is clearly seen that H_1 shifts toward higher magnetic field with increasing pressure. H_n is related to the exchange coupling $-2J_{NN}S_i \cdot S_i$ of Mn spins by³ $H_n=2n |J_{NN}|(g\mu_B)^{-1}+H_d$, where g and μ_B are the g-parameter of a Mn ion and the Bohr magneton, respectively, and $H_a \approx 1.5 \,\mathrm{T}$ is the correction due to the distant-neighbor Mn-Mn interactions. The experimental results shown in Fig.2 indicate that U_{NN} is significantly enlarged by pressure.

When pairs of TM ions coexist with isolated ions, the mean spin <S> is given by $<S>=f_1<S_2>+(f_2/2)<S_p>$ with the probabilities f_1 and f_2 that a TM ion is isolated and paired with another TM

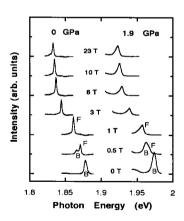


Figure 1. Photoluminescence spectrum due to the A-exciton in Cd_{0.98}Mn_{0.06}Se under various magnetic fields at 0 and 1.9 GPa. The features F and B are due to free and bound excitons, respectively.

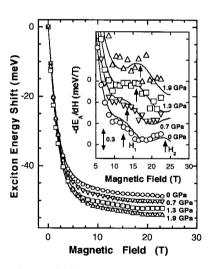


Figure 2. Field-induced energy shift of the free exciton line in $\mathrm{Cd}_{0.95}\mathrm{Mn}_{0.00}\mathrm{Se}$ under 0 (\bigcirc), 0.7 (\bigcirc), 1.3 (\square), and 1.9 (\square) GPa. The inset shows the derivative of the exciton energy with respect to the external magnetic field. The solid lines are the theoretical curves. Arrows show the field positions H_1 and H_2 .

ion, respectively. For Mn²⁺ ions, $\langle S_{\uparrow} \rangle$ is given by a modified Brillouin function for the spin of S = 5/2, while $\langle S_{\rho} \rangle$ has been formulated in Ref.[3] as a function of H and temperature. In the case of $H \parallel c$, δE_{λ} is given to a good approximation by

$$\delta E_{\rm A} = -\frac{1}{2} |N_0 \beta_{\rm hyb}| x < S > + E_{\rm Z,d},$$
 (1)

where $N_0 \beta_{\rm hyb}$ is the exchange constant of the p-d hybridization term and $E_{\rm Z,d}$ represents the linear Zeeman and diamagnetic shifts of the A-exciton due to the external magnetic field. In Fig. 2 the theoretical curves of $\delta E_{\rm A}$ are compared with experimental results. The calculations are performed by taking $N_0 \beta_{\rm hyb}$ and $J_{\rm NN}$ as the adjustable parameters. The calculated curves agree well with the experimental results. Figure 3 shows the relative pressure de-

pendence of $|N_0\beta_{hyb}|$ and $|J_{NN}|$ extracted from this analysis. The pressure coefficients are found to be 7.0±0.1 %/GPa and 20±2 %/GPa for $|N_0\beta_{hyb}|$ and $|J_{NN}|$, respectively. According to recent theoretical investigations, ^{6.7} these kinetic-exchange constants are given well by

$$N_0\beta_{\rm hyb} = -\frac{16}{S}V_{pd}^2\left(\frac{1}{\Delta} + \frac{1}{U-\Delta}\right), \tag{2}$$

and

$$J_{\rm NN} = -\frac{1}{2S^2} \frac{V_{pd}^4}{\Delta^2} \left(\frac{1}{U} + \frac{1}{\Delta} \right) j. \tag{3}$$

The coefficient j in Eq.(3) is a dimensionless constant. At 1 atm we have $N_0\beta_{hyb}=-1.37$ eV[Ref. 8], $J_{NN}=-6.4\times10^{-4}$ eV, U=7.6 eV[Ref. 6], and $\Delta=4.2$ eV[Ref. 6]. Thus Eqs.(2) and (3) yield j=2.35.

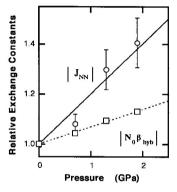


Figure 3. Pressure dependencies of $J_{\rm NN}$ and $N_{\rm o}\beta_{\rm hys}$. The solid and dotted lines show the pressure coefficients of 20% /GPa and 7% /GPa, respectively.

Harrison's scaling theory 9 predicts that the transfer integral V_{pd} depends on the Mn-Se bond length l as $l^{-7/2}$. Therefore, the linear compressibility $\kappa = 0.62~\%/\text{GPa}$ of the lattice gives $d\ln V_{pd}^2/dP \approx 4.3~\%/\text{GPa}$ and $d\ln V_{pd}^4/dP \approx 8.7~\%/\text{GPa}$. The discrepancies by a factor of about 2 seen in comparison with the experimental values, $d\ln |N_0\beta_{\text{hyb}}|/dP \approx 7\%/\text{GPa}$ and $d\ln |J_{\text{NN}}|/dP \approx 20\%/\text{GPa}$, support the notion that U and/or Δ vary with pressure. Figure 4 shows the pressure dependencies of U and Δ calculated from Eqs.(2) and (3) with experimental values of $N_0\beta_{\text{hyb}}$ and J_{NN} , and V_{pd}^2 and V_{pd}^4 scaled from Harrison's formula. Both U and Δ turn out to be reduced by pressure at rates of -0.18 and -0.12~eV/GPa, respectively. The magnitude of the relative reduction of U, $|d\ln U/dP| \approx 2.4\%/\text{GPa}$, is as great as the magnitude of the relative increase of V_{pd} , $d\ln |V_{pd}|/dP \approx 2.2\%/\text{GPa}$. The observed reduction of U is qualitatively explained by the enhancement of the screening effect, due to

valence electrons, resulting from an increase in the p-d hybridization. The strong sensitivity of the exchange interactions to the change in Δ leads us to envisage that the giant magneto-optical properties of a diluted magnetic semiconductor will be affected by quantum lattice structures, since the valence band is altered by the quantum confinement of electrons.

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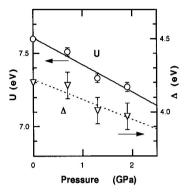


Figure 4. Pressure dependencies of U and Δ . The solid and dashed lines are the liner fits to the experimental data of U and Δ , respectively.

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